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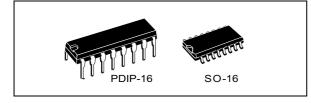




HCF4051

Single 8-channel analog multiplexer/demultiplexer

Datasheet - production data



Features

- Low "ON" resistance: 125 Ω (typ.)
- Over 15 V p.p signal-input range for $V_{DD} - V_{FF} = 15 V$
- High "OFF" resistance, channel leakage: \pm 100 pA (typ.) at V_{DD} - V_{EE} = 18 V
- Binary address decoding on chip
- High degree of linearity: < 0.5 % distortion typ. at f_{IS} = 1 KHz, V_{IS} = 5 V_{pp} , V_{DD} - $V_{SS} \ge$ 10 V, $R_{I} = 10 k\Omega$
- Very low guiescent power dissipation under all digital control input and supply conditions: $0.2 \,\mu\text{W}$ (typ.) $V_{\text{DD}} - V_{\text{SS}} = V_{\text{DD}} - V_{\text{EE}} = 10 \,\text{V}$
- Matched switch characteristics: $R_{ON} = 5 \Omega (typ.)$ for $V_{DD} - V_{FF} = 15 V$
- Wide range of digital and analog signal levels: digital 3 to 20, analog to 20 V p.p.
- Quiescent current specified up to 20 V
- 5 V, 10 V and 15 V parametric ratings
- ESD performance
 - HBM: 2 kV
 - MM: 200 V
 - CDM: 750 V

- Input leakage current I_I = 100 nA (max.) at V_{DD} = 18 V, T_A = 25 °C
- 100 % tested for quiescent current

Applications

- Automotive
- Industrial
- Computer
- Consumer

Description

The HCF4051 device is a monolithic integrated circuit fabricated in MOS (metal oxide semiconductor) technology available in SO-16 and PDIP-16 packages.

The HCF4051 analog multiplexer/demultiplexer is a digitally controlled analog switch having low ON impedance and very low OFF leakage current. This multiplexer circuit dissipates extremely low quiescent power over the full VDD - VSS and V_{DD} - V_{FF} supply voltage range, independent of the logic state of the control signals.

This device is a single 8-channel multiplexer having three binary control inputs, A, B, and C, and an inhibit input. The three binary signals select 1 of 8 channels to be turned on, and connect one of the 8 inputs to the output. When a logic "1" is present at the inhibit input terminal all channels are off.

Order code	Temperature range	Package	Packaging	Marking				
HCF4051M013TR	-55/+125 °C	SO-16	Tape and reel	HCF4051				
HCF4051YM013TR ⁽¹⁾	-40/+125 °C	SO16 (automotive version)	Tape and Teel	HCF4051Y				
HCF4051BEY	-55/+125 °C	PDIP-16	Tube	HCF4051BE				

Table 1. Device summary

1. Qualification and characterization according to AEC Q100 and Q003 or equivalent, advanced screening according to AEC Q001 and Q002 or equivalent.

April 2013

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This is information on a product in full production.

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1	Pin information



1 Pin information



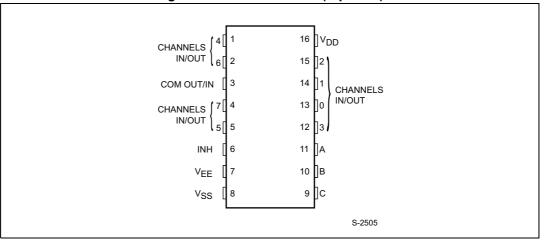


Table 2. Pin description

Pin no.	Symbol	Name and function
11, 10, 9	A, B, C	Binary control inputs
6	INH	Inhibit inputs
13, 14, 15, 12, 1, 5, 2, 4	0 to 7 channel IN/OUT	Independent inputs/outputs
3	COM OUT/IN	Common output/input
7	V _{EE}	Supply voltage
8	V _{SS}	Negative supply voltage
16	V _{DD}	Positive supply voltage

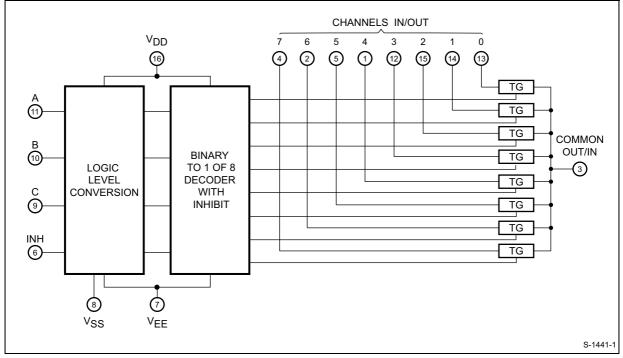


2 Functional description

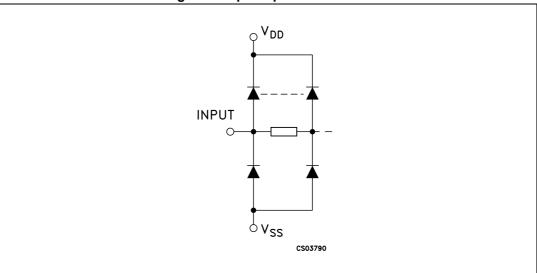
Input	"ON" channel (S)			
Inhibit	С	В	Α	"ON" channel (S)
0	0	0	0	0
0	0	0	1	1
0	0	1	0	2
0	0	1	1	3
0	1	0	0	4
0	1	0	1	5
0	1	1	0	6
0	1	1	1	7
1	Х	Х	Х	None

Table 3. Truth table











3 Electrical characteristics

Absolute maximum ratings are those values beyond which damage to the device may occur. Functional operation under these conditions is not implied. All voltage values are referred to V_{SS} pin voltage.

Symbol	Parameter	Value	Unit
V _{DD}	Supply voltage	-0.5 to +22	V
VI	DC input voltage	-0.5 to V _{DD} + 0.5	v
I _I	DC input current	±10	mA
Р	Power dissipation per package	500 ⁽¹⁾	mW
PD	Power dissipation per output transistor	100	mvv
T _{op}	Operating temperature	-55 to +125	0°
T _{stg}	Storage temperature	-65 to +150	C

Table 4. Absolute maximum ratings

1. 500 mW at 65 °C; derate to 300 mW by 10 mW/°C from 65 °C to 85 °C.

Table 5. Recommended operating conditions

Symbol	Parameter	Value	Unit
V _{DD}	Supply voltage	3 to 20	V
VI	Input voltage	0 to V _{DD}	v
T _{op}	Operating temperature	-55 to 125	°C

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		Test	t conditi	on	_	Value					
Symbol Parameter	Parameter	V _{IS}	V _{EE}	vss	V _{DD}	T _A = 25 °C		°C	-55 to 125 °C		Unit
		(V)	(V)	(V)	(V)	Min.	Тур.	Max.	Min.	Max.	
	Quiescent device				5		0.04	5		150	
۱ _L	current (all switches				10		0.04	10		300	μA
۰L	ON or all switches OFF)				15		0.04	20		600	μι
	,				20		0.08	100		3000	
Switch											
					5		470	1050		1200	
R _{ON}	Resistance	$0 \leq V_{I} \leq V_{DD}$	0	0	10		180	400		520	
					15		125	280		360	Ω
	Resistance Δ_{RON}				5		10				22
D _{ON}	(between any 2 of 4 $0 \le V_I \le V_{DD}$ switches)	0	0	10		10					
	switches)				15		5				
OFF ⁽¹⁾	Channel leakage current (all channels OFF) (COMMON O/I)		0	0	18		±0.1	100		1000	nA
OFF ⁽¹⁾	Channel leakage current (any channel OFF)		0	0	18		±0.1	100		1000	
Cl	Input capacitance						5				
C _O	Output capacitance		-5	-5	5		30				pF
C _{IO}	Feedthrough						0.2				
Control (address or inhibit)										
					5			1.5		1.5	
V _{IL}	Input low voltage		V _{EE} :	= V _{SS}	10			3		3	
		= V _{DD} through		1KΩ V _{SS}	15			4		4	
		¹ ΚΩ	l _{IS} <	2μΑ	5	3.5			3.5		V
V_{IH}	V _{IH} Input high voltage			ll OFF inels)	10	7			7		
					15	11			11		
I _{IH,} I _{IL}	Input leakage current	$V_{I} = 0/$	′18 V		18		±10 ⁻³	±0.1		±1	μA
CI	Input capacitance						5	7.5			pF

Table 6. DC specifications

1. Determined by minimum feasible leakage measurement for automating testing.



	Test condition						Value			Unit	
Parameter	V _{EE} (V)	R L (ΚΩ)	f _l (KHz)	V _I (V)	V _{SS} (V)	V _{DD} (V)		Min.	Тур.	Max.	
D						5			30	60	
Propagation delay time (signal input to output)		200				10			15	30	ns
						15			11	20	
Frequency response channel "ON"	=V _{SS}	1		5 ⁽²⁾		10	V _O at common OUT/IN		20		
(sine wave input) at 20 log V _O /V _I = -3 dB	- v _{SS}			J		10	V _O at any channel		60		
Feedthrough (all channels OFF)	=V _{SS}	1		5 ⁽²⁾		10	V _O at common OUT/IN		12		MHz
at 20 log $V_0/V_1 = -40 \text{ dB}$	- v _{SS}	1		50		10	V _O at any channel		8		
Frequency signal crosstalk at 20 log $V_0/V_1 = -40 \text{ dB}$	= V _{SS}	1		5 ⁽²⁾		10	Between any 2 channels		3		
				2 ⁽²⁾		5			0.3		
Sine wave distortion f _{IS} = 1 KHz sine wave	$= V_{SS}$	10	1	3 ⁽²⁾		10			0.2	9	%
13				5 ⁽²⁾		15			0.12		
Control (address or inhib	oit)										
	0				0	5			360	720	
Propagation delay:	0				0	10			160	320	
address to signal OUT (channels ON or OFF)	0				0	15			120	240	
	-5				0	5			225	450	
	0				0	5			360	720	
Propagation delay: inhibit	0	1			0	10			160	320	
to signal OUT (channel turning ON)	0	1			0	15			120	240	ns
-	-10				0	5]		200	400	
Propagation delay: inhibit to signal OUT (channel turning OFF)	0				I	5			200	450	
	0	10				10			90	210	
	0	10				15			70	160	
	-10					5			130	300	
Address or inhibit to signal crosstalk	0	10 ⁽¹⁾			0	10	V _C = V _{DD} - V _{SS} (square wave)		65		mV peak

Table 7. Dynamic electrical characteristics $(T_{amb} = 25 \text{ °C}, C_L = 50 \text{ pF}, \text{ all input square wave rise and fall time = 20 ns})^{(1)}$

1. Both ends of channel.

2. Peak-to-peak voltage symmetrical about (V_{DD} - V_{EE}) /2.



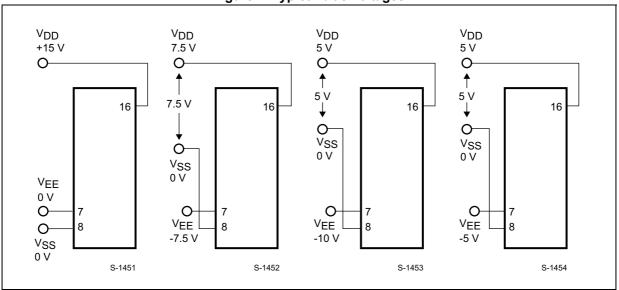


Figure 4. Typical bias voltages

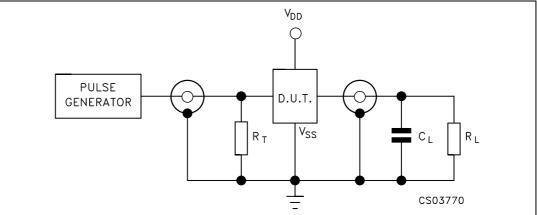
1. The ADDRESS (digital-control inputs) and INHIBIT logic levels are : "0" = V_{SS} and "1" = V_{DD}. The analog signal (through the TG) may swing from V_{EE} to V_{DD}.

Special considerations

Control of analog signals up to 20 V peak-to-peak can be achieved by digital signal amplitudes of 4.5 to 20 V (if $V_{DD} - V_{SS} = 3 V$, a $V_{DD} - V_{EE}$ of up to 13 V can be controlled; for $V_{DD} - V_{EE}$ level differences above 13 V, a $V_{DD} - V_{SS}$ of at least 4.5 V is required).

For example, if V_{DD} = +5, V_{SS} = 0, and V_{EE} = -13.5, analog signals from -13.5 V to 4.5 V can be controlled by digital inputs of 0 to 4.5 V. In certain applications, the external load resistor current may include both V_{DD} and signal-line components. To avoid drawing V_{DD} current when switch current flows into the transmission gate inputs, the voltage drop across the bidirectional switch must not exceed 0.8 V (calculated from R_{ON} values shown in *Table 6: DC specifications*). No V_{DD} current flows through R_L if the switch current flows into lead 3.





1. C_L = 50 pF or equivalent (includes jig and probe capacitance) R_L = 200 K Ω R_T = Z_{OUT} of pulse generator (typically 50 Ω).



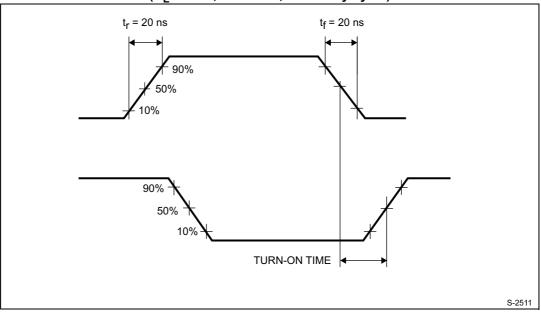
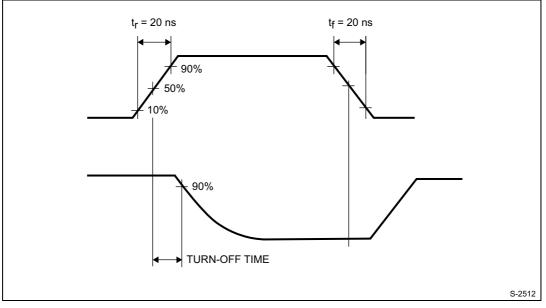


Figure 6. Waveform 1: channel turned ON (R_L = 1 K Ω , f = 1 MHz; 50 % duty cycle)

Figure 7. Waveform 2: channel turned OFF (R_L = 1 KW, f = 1 MHz; 50 % duty cycle)





4 Package information

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK[®] packages, depending on their level of environmental compliance. ECOPACK specifications, grade definitions and product status are available at: *www.st.com*. ECOPACK is an ST trademark.



4.1 PDIP-16 (0.25) package information

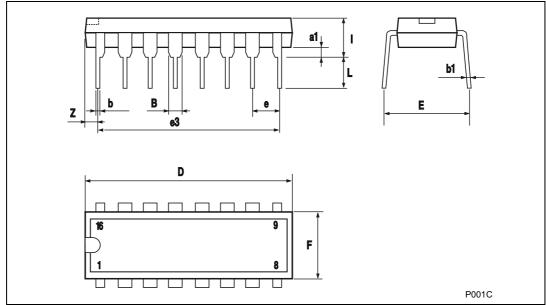


Figure 8. PDIP-16 (0.25) package mechanical drawing

Table 8. PDIP-16 (0.25) package mechanical data

	Dimensions									
Symbol		mm			inch					
	Min.	Тур.	Max.	Min.	Тур.	Max.				
a1	0.51			0.020						
В	0.77		1.65	0.030		0.065				
b		0.5			0.020					
b1		0.25			0.010					
D			20			0.787				
E		8.5			0.335					
е		2.54			0.100					
e3		17.78			0.700					
F			7.1			0.280				
I			5.1			0.201				
L		3.3			0.130					
Z			1.27			0.050				



4.2 SO-16 package information

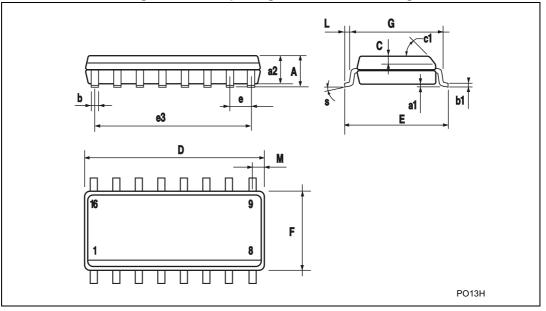


Figure 9. SO-16 package mechanical drawing

Table 9. SO-16 package mechanical data

	Dimensions									
Symbol		mm		inch						
	Min.	Тур.	Max.	Min.	Тур.	Max.				
А			1.75			0.068				
a1	0.1		0.2	0.003		0.007				
a2			1.65			0.064				
b	0.35		0.46	0.013		0.018				
b1	0.19		0.25	0.007		0.010				
С		0.5			0.019					
c1			45° ((typ.)						
D	9.8		10	0.385		0.393				
Е	5.8		6.2	0.228		0.244				
е		1.27			0.050					
e3		8.89			0.350					
F	3.8		4.0	0.149		0.157				
G	4.6		5.3	0.181		0.208				
L	0.5		1.27	0.019		0.050				
М			0.62			0.024				
S			8 ° (max.)	•					



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5 Ordering information

Table	10.	Order	codes
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Order code	Temperature range	Package	Packaging	Marking
HCF4051M013TR	-55/+125 °C	SO-16		HCF4051
HCF4051YM013TR ⁽¹⁾	-40/+125 °C	SO16 (automotive version)	Tape and reel	HCF4051Y
HCF4051BEY	-55/+125 °C	PDIP-16	Tube	HCF4051BE

1. Qualification and characterization according to AEC Q100 and Q003 or equivalent, advanced screening according to AEC Q001 and Q002 or equivalent.

6 Revision history

Date	Revision	Changes		
26-Oct-2012	2	Updated <i>Features</i> (added ESD values), added <i>Applications</i> . Updated <i>Table 1</i> (reformatted table, added order codes, temperature range, marking, updated package and packaging). Updated <i>Description</i> (unified part numbers, moved to page 2). Updated <i>Section 2</i> to <i>Section 4</i> (added titles and numbering). Updated <i>Table 6</i> (removed -40/+85° temperature range). Reformatted <i>Section 4</i> (added ECOPACK text, <i>Figure 8, Figure 9,</i> <i>Table 8</i> , and <i>Table 9</i>). Minor corrections throughout document.		
30-Apr-2013	3	Updated <i>Features</i> (ESD values) Added <i>Section 5: Ordering information</i>		

Table 11. Document revision history	Table 11.	Document	revision	history
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